1. Safety Precautions

1-1. Repair Precaution

 Before attempting any repair or detailed tuning, shield the device from RF noise or static electricity discharges.

(Use only antistatic glove and strape.)

- Do not touch metallic parts or circuits with your bare hands as device(parts, circuits, etc) may be corroded.
- Use only demagnetized tools that are specifically designed for small electronic repairs, as most electronic parts are sensitive to electromagnetic forces.
- Use only high quality screwdrivers when servicing products. Low quality screwdrivers can easily damage the heads of screws.
- Use only conductor wire of the properly gauge and insulation for low resistance, because of the low margin of error of most testing equipment.
 We recommend 22-gauge twisted copper wire.
- Hand-soldering is not recommended, because printed circuit boards (PCBs) can be easily damaged, even with relatively low heat. Never use a soldering iron with a power rating of more than 100 watts and use only lead-free solder with a melting point below 250°C (482°F).
- Prior to disassembling the battery charger for repair, ensure that the AC power is disconnected.
 Always use the replacement parts that are registered in the SEC system. Third-party replacement parts may not function properly.

1. Safety Precautions

1-2. ESD(Electrostatically Sensitive Devices) Precaution

Many semiconductors and ESDs in electronic devices are particularly sensitive to static discharge and can be easily damaged by it. We recommend protecting these components with conductive anti-static bags when you store or transport them.

- Always use an anti-static strap or wristband and remove electrostatic buildup or dissipate static electricity from your body before repairing ESDs.
- Ensure that soldering irons have AC adapter with ground wires and that the ground wires are properly connected.
- Use only desoldering tools with plastic tips to prevent static discharge.
- Properly shield the work environment from accidental electrostatic discharge before opening packages containing ESDs.
- The potential for static electricity discharge may be increased in low humidity environments, such as air-conditioned rooms. Increase the airflow to the working area to decrease the chance of accidental static electricity discharges.

2-1-1. GSM General Specification [SM-A013F]

ltem		GSM 850	EGSM 900	DCS1800
Freq. Ba	ınd[MHz]	824~849	880~915	1710~1785
Uplink/E	Downlink	869~894	925~960	1805~1880
ARFCN	N range	128~251	0~124 & 975~1023	512~885
Tx/Rx s	spacing	45MHz	45MHz	95MHz
Mod. E	Bit rate/	270.833kbps	270.833kbps	270.833kbps
Bit P	eriod	3.692us	3.692us	3.692us
	ot Period/	576.9us	576.9us	576.9us
Frame	Period	4.615ms	4.615ms	4.615ms
	GSM/	GMSK/	GMSK/	GMSK/
Modulation	EGPRS	8PSK	8PSK	8PSK
MS F	Power	33dBm~5dBm	33dBm~5dBm	30dBm~0dBm
		4(GMSK)	4(GMSK)	1(GMSK)
Power	Class	E2(8PSK)	E2(8PSK)	E2(8PSK)
Sensitivity		-102dBm	-102dBm	-100dBm
TDMA	A Mux	8	8	8

2-1-2. GSM General Specification [SM-A013M]

Item		GSM 850	EGSM 900	DCS1800	PCS1900
Freq. Ba	nd[MHz]	824~849	880~915	1710~1785	1850~1910
Uplink/D	ownlink	869~894	925~960	1805~1880	1930~1990
ARFCN	I range	128~251	0~124 & 975~1023	512~885	512~810
Tx/Rx s	spacing	45MHz	45MHz	95MHz	80MHz
Mod. B	sit rate/	270.833kbps	270.833kbps	270.833kbps	270.833kbps
Bit Po	eriod	3.692us	3.692us	3.692us	3.692us
Time Slo		576.9us	576.9us	576.9us	576.9us
Frame	Period	4.615ms	4.615ms	4.615ms	4.615ms
	GSM/	GMSK/	GMSK/	GMSK/	GMSK/
Modulation	EGPRS	8PSK	8PSK	8PSK	8PSK
MS P	ower	33dBm~5dBm	33dBm~5dBm	30dBm~0dBm	30dBm~0dBm
_		4(GMSK)	4(GMSK)	1(GMSK)	1(GMSK)
Power	Class	E2(8PSK)	E2(8PSK)	E2(8PSK)	E2(8PSK)
Sensitivity		-102dBm	-102dBm	-100dBm	-100dBm
TDMA	A Mux	8	8	8	8

2-1-3. GSM General Specification [SM-A013G]

ltem		GSM 850	EGSM 900	PCS1900
Freq. Ba	ınd[MHz]	824~849	880~915	1850~1910
Uplink/E	Downlink	869~894	925~960	1930~1990
ARFCN	N range	128~251	0~124 & 975~1023	512~810
Tx/Rx s	spacing	45MHz	45MHz	80MHz
Mod. E	Bit rate/	270.833kbps	270.833kbps	270.833kbps
Bit P	eriod	3.692us	3.692us	3.692us
	ot Period/	576.9us	576.9us	576.9us
Frame	Period	4.615ms	4.615ms	4.615ms
	GSM/	GMSK/	GMSK/	GMSK/
Modulation	EGPRS	8PSK	8PSK	8PSK
MS F	Power	33dBm~5dBm	33dBm~5dBm	30dBm~0dBm
		4(GMSK)	4(GMSK)	1(GMSK)
Power	Class	E2(8PSK)	E2(8PSK)	E2(8PSK)
Sensitivity		-102dBm	-102dBm	-100dBm
TDMA	A Mux	8	8	8

2-2. GSM Tx Power Class

TX Power control level	GSM850	TX Power control level	EGSM900	TX Power control level	DCS1800	TX Power control level	PCS1900
5	33±2 dBm	5	33±2 dBm	0	30±3 dBm	0	30±3 dBm
6	31±2 dBm	6	31±2 dBm	1	28±3 dBm	1	28±3 dBm
7	29±2 dBm	7	29±2 dBm	2	26±3 dBm	2	26±3 dBm
8	27±2 dBm	8	27±2 dBm	3	24±3 dBm	3	24±3 dBm
9	25±2 dBm	9	25±2 dBm	4	22±3 dBm	4	22±3 dBm
10	23±2 dBm	10	23±2 dBm	5	20±3 dBm	5	20±3 dBm
11	21±2 dBm	11	21±2 dBm	6	18±3 dBm	6	18±3 dBm
12	19±2 dBm	12	19±2 dBm	7	16±3 dBm	7	16±3 dBm
13	17±2 dBm	13	17±2 dBm	8	14±3 dBm	8	14±3 dBm
14	15±2 dBm	14	15±2 dBm	9	12±4 dBm	9	12±4 dBm
15	13±2 dBm	15	13±2 dBm	10	10±4 dBm	10	10±4 dBm
16	11±3 dBm	16	11±3 dBm	11	8±4 dBm	11	8±4 dBm
17	9±3 dBm	17	9±3 dBm	12	6±4 dBm	12	6±4 dBm
18	7±3 dBm	18	7±3 dBm	13	4±4 dBm	13	4±4 dBm
19	5±3 dBm	19	5±3 dBm	14	2±5 dBm	14	2±5 dBm
-	-	-	-	15	0±5 dBm	15	0±5 dBm

2-3-1. WCDMA General Specification [SM-A013F/G]

ltem	WCDMA2100(B1)	WCDMA850(B5)	WCDMA900(B8)
Freq. Band[MHz]	1920~1980	824~849	880~915
Uplink/Downlink	2110~2170	869~894	925~960
ARFCN range	UL: 9612~9888	UL: 4132~4233	UL: 2712~2868
	DL: 10562~10838	DL: 4357~4458	DL: 2937~3088
Tx/Rx spacing	190MHz	45MHz	45MHz
Mod. Bit rate/ Bit Period	42.2Mbps(DL) 5.42Mbps(UL)	42.2Mbps(DL) 5.42Mbps(UL)	42.2Mbps(DL) 5.42Mbps(UL)
Time Slot Period/ Frame Period	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms
Modulation	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM
MS Power (dBm)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)
Power Class	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)
Sensitivity	-106dBm	-104dBm	-103dBm

2-3-2. WCDMA General Specification [SM-A013M]

Item	WCDMA2100(B1)	WCDMA1900(B2)	WCDMA AWS(B4)	WCDMA850(B5)	WCDMA900(B8)
Freq. Band[MHz]	1920~1980	1850~1910	1710~1755	824~849	880~915
Uplink/Downlink	2110~2170	1930~1990	2110~2155	869~894	925~960
ARFCN range	UL: 9612~9888	UL: 9262~9538	UL: 1312~1513	UL: 4132~4233	UL: 2712~2868
7ttt Olv range	DL: 10562~10838	DL: 9662~9938	DL: 1537~1738	DL: 4357~4458	DL: 2937~3088
Tx/Rx spacing	190MHz	80MHz	400MHz	45MHz	45MHz
Mod. Bit rate/	42.2Mbps(DL)	42.2Mbps(DL)	42.2Mbps(DL)	42.2Mbps(DL)	42.2Mbps(DL)
Bit Period	5.42Mbps(UL)	5.42Mbps(UL)	5.42Mbps(UL)	5.42Mbps(UL)	5.42Mbps(UL)
Time Slot Period/ Frame Period	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms
Modulation	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM
MS Power (dBm)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)
Power Class	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)
Sensitivity	-106dBm	-104dBm	-106dBm	-104dBm	-103dBm

2-4. LTE General Specification

Item	LTE Band1	LTE Band3	LTE Band5	LTE Band7	LTE Band8
Freq. Band[MHz] Uplink/Downlink	1920~1980 2110~2170	1710~1785 1805~1880	824~849 869~894	2500~2570 2620~2690	880~915 925~960
ARFCN range	UL:18000~18599 DL:0~599	UL:19200~19949 DL:1200~1949	UL:20400~20649 DL:2400~2649	UL:20750~21449 DL:2750~3449	UL:21450-21799 DL:3450-3799
Tx/Rx spacing (MHz)	190	95	45	120	45
Channel Bandwidth (MHz)	5/10/15/20	1.4/3/5/10/15/20	1.4/3/5/10	5/10/15/20	1.4/3/5/10
Modulation	QPSK,16/64QAM 256QAM(DL only)				
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm)	-96.3	-93.3	-94.3	-94.3	-93.3

[SM-A013F]

Item	LTE Band20	LTE Band38	LTE Band40	LTE Band41
Freq. Band[MHz] Uplink/Downlink	832~862 791~821	2570~2620	2300~2400	2496~2690
ARFCN range	UL:24150~24449 DL:6150~6449	UL/DL:37750 ~ 38249	UL/DL:38650 ~ 39649	UL/DL:39650 ~ 41589
Tx/Rx spacing (MHz)	-41	0	0	0
Channel Bandwidth (MHz)	5/10/15/20	5/10/15/20	5/10/15/20	5/10/15/20
Modulation	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm)	-93.3	-96.3	-96.3	-94.3

[SM-A013M]

Item	LTE Band2	LTE Band4	LTE Band28	LTE Band66
Freq. Band[MHz] Uplink/Downlink	1850~1910 1930~1990	1710~1755 2110~2155	703~748 758~803	1710~1780 2110~2200
ARFCN range	UL:18600~19199 DL:600~1199	UL:19950~20399 DL:1950~2399	UL:27210~27659 DL:9210~9659	UL:131972~132671 DL:66436~67335
Tx/Rx spacing (MHz)	80	400	55	400
Channel Bandwidth (MHz)	1.4/3/5/10/15/20	1.4/3/5/10/15/20	3/5/10/15/20	1.4/3/5/10/15/20
Modulation	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm)	-94.3	-96.3	-94.8	-95.8

[SM-A013G]

[ON AUTOU]					
Item	LTE Band20	LTE Band28	LTE Band38	LTE Band40	LTE Band41
Freq. Band[MHz] Uplink/Downlink	832~862 791~821	703~748 758~803	2570~2620	2300~2400	2496~2690
ARFCN range	UL:24150~24449 DL:6150~6449	UL:27210~27659 DL:9210~9659	UL/DL:37750 ~ 38249	UL/DL:38650 ~ 39649	UL/DL:39650 ~ 41589
Tx/Rx spacing (MHz)	-41	55	0	0	0
Channel Bandwidth (MHz)	5/10/15/20	3/5/10/15/20	5/10/15/20	5/10/15/20	5/10/15/20
Modulation	QPSK,16/64QAM 256QAM(DL only)				
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm))	-93.3	-94.8	-96.3	-96.3	-94.3

3. Product Function

Specification

Item	Description
os	Android GO V10.0
SM-A013F Network	2G - GSM: GSM850 / GSM900 / DCS1800 3G - WCDMA: B1 / B5 / B8 4G LTE - FDD: B1 / B3 / B5 / B7 / B8 / B20 - TDD: B38 / B40 / B41
SM-A013M Network	2G - GSM: GSM850 / GSM900 / DCS1800 / PCS1900 3G - WCDMA: B1 / B2 / B4 / B5 / B8 4G LTE - FDD: B1 / B2 / B3 / B4 / B5 / B7 / B8 / B28 / B66
SM-A013G Network	2G - GSM: GSM850 / GSM900 / DCS1800 3G - WCDMA: B1 / B5 / B8 4G LTE - FDD: B1 / B3 / B5 / B7 / B8 / B20 / B28 - TDD: B38 / B40 / B41
Battery	3,000mAh
Processor	MT6739WW, 1.5GHz
Connectivity	GPS, Glonass, BT V5.0, USB 2.0, WiFi 802.11 b/g/n (2.4GHz)
Camera	Rear: 8.0MP, A/F, F2.2 Front: 5.0MP, F2.4
Display	5.3" HD, 1480 x 720, PLS TFT LCD
RAM	1GB
ROM	16GB
Sensor	Accelerometer, Virtual Proximity Sensing

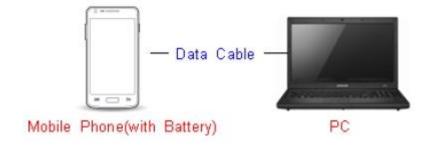
6-1. S/W Update

6-1-1. Preparation

S/W Update program: Fenrir 5.17.xxxx

- Mobile Phone
- · Data Cable

*** Settings**





Data Cable: GH39-02042B

6-1-2. How to use 'Fenrir' S/W update program.







- 1) Launch Fenrir by clicking on the icon on the desktop
- SVH (Fenrir_Home): It uses Home binary which does not have user data area in the memory when flashed to a device. (Keep user data)
- SVC (Fenrir_Factory): It uses Factory binary which erases all user data in the memory when flashed to a device. (Clear user data)
- SVA (Fenrir_All): It uses Factory and Home binaries. you can download Home and Factory binary in a PC. (but requires double HDD storage and NW traffic)
- 2) Input ID & password
- *You need to reset the ID information in case of PC change and format and repair, hard disk change.

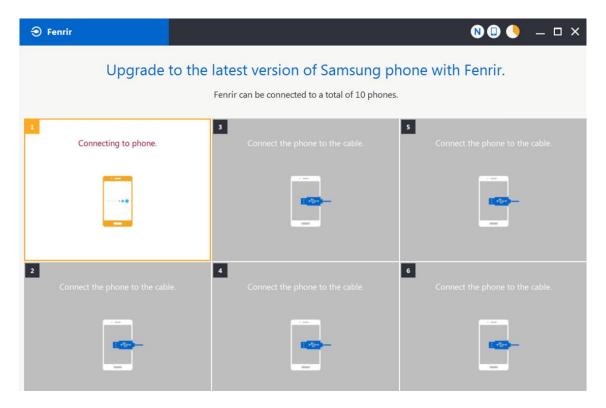


3) Ensure device has sufficient charge (at least 20%) to start firmware update.



4) Connect the device to PC via data cable.

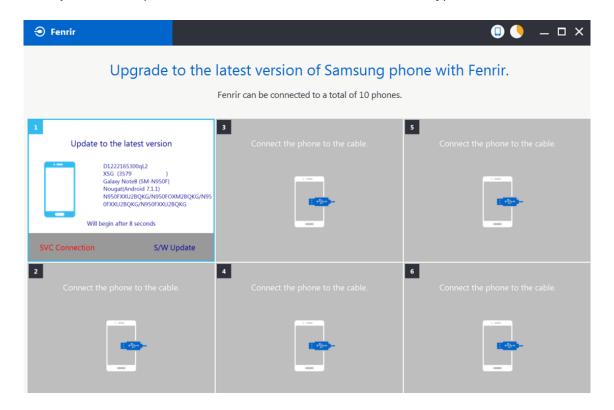
5) Upon USB connection, you will be presented with below screen.



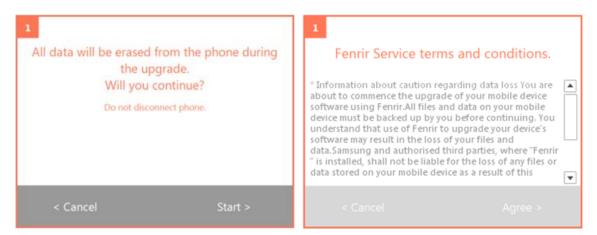
6) Once device is detected, you will be presented with below screen.

To update S/W, select "S/W Update" or to exit select "SVC Connection".

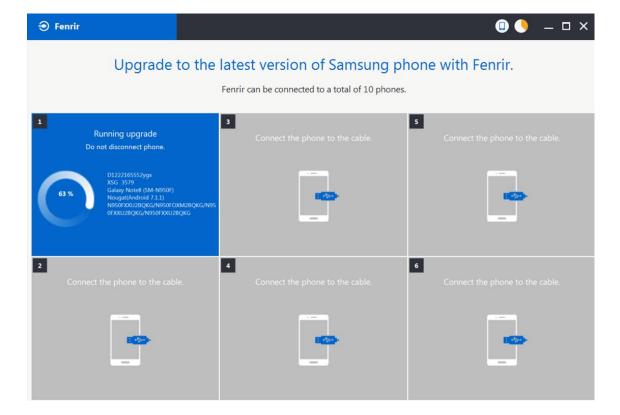
If you select "SVC Connection", only Fenrir connection history (record) will be stored in the FUS server to support warranty validation. (This is known as "Service Connection" history)



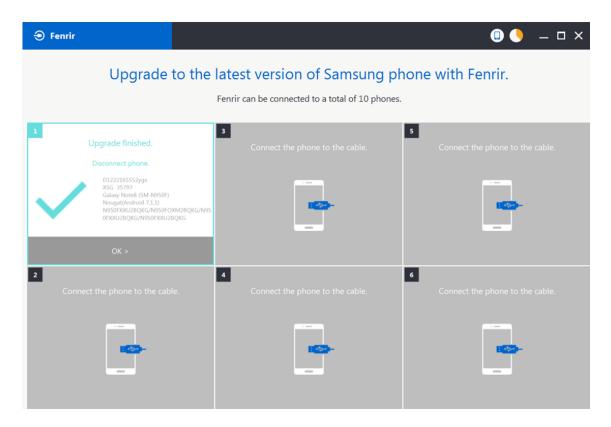
7) Once Fenrir starts, application will display the below screen. And select the Start button & Agree button.



8) The status circle increases as the update installs. The update process takes approximately 5-10 minutes to complete. Do not disconnect the device from USB during processing.



9) Once complete, application will present the below screen indicating update complete. Click Ok and detach device from USB.



6-2. How to use 'Odin' program

S/W Update via Fenrir is mandatory.
Below is the method to use 'Odin' program in any specific case.

6-2-1. Preparation

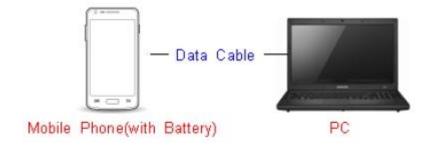
• Installation program: Odin3 v3.12.10.exe

• Mobile Phone

• Data Cable

• S/W Binary files (downloaded from GSPN)

*** Settings**

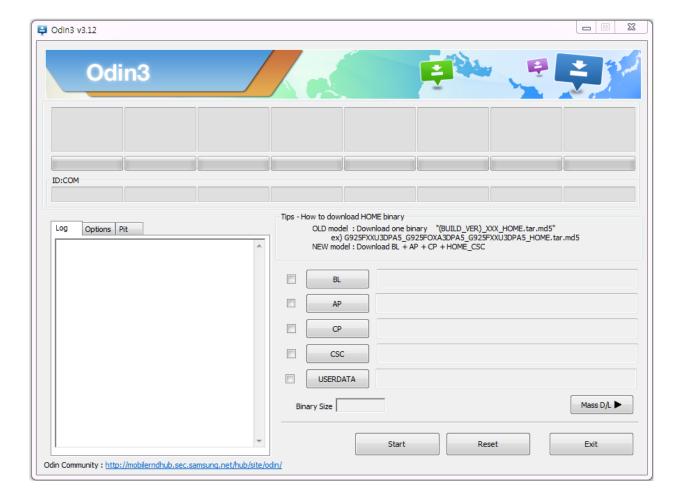




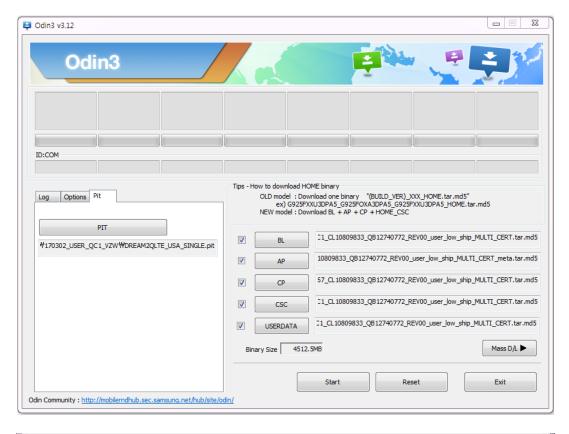
Data Cable: GH39-02042B

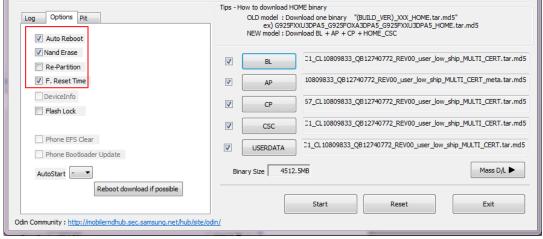
6-2-2. S/W Installation Program (Downloader program)

Open up the S/W Installation Program by executing the "Odin3 v3.12.10.exe"



- 1. Enable the check mark by click on the following options
- Check Auto Reboot, F. Reset Time, Nand Erase
- Check PIT
- Check BOOTLOADER, PDA, PHONE, CSC and USERDATA Files
- * Note: "Odin v3.12.10 or above" checks MD5 checksum just after file selection.





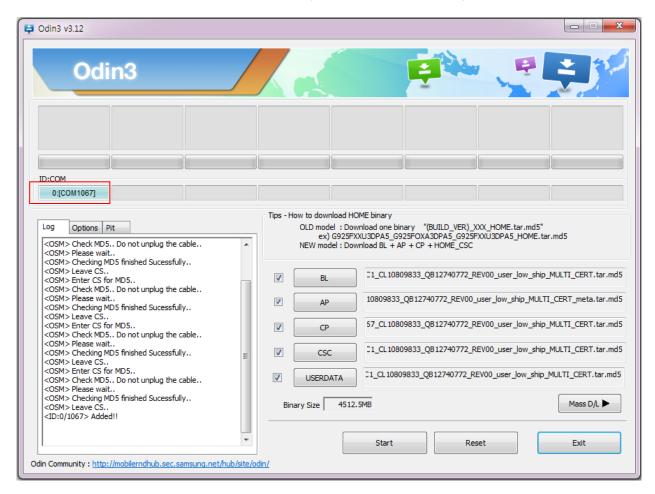
2. Enter into Download Mode

- Enter into Download Mode by inserting data cable while pressing Volume Down button simultaneously followed by pressing Volume up button as a direction of the phone.



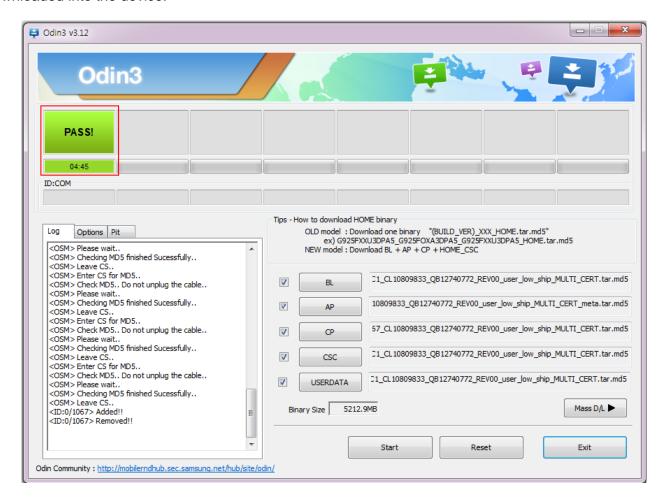
3. Connect the device to PC via Data Cable.

Make sure that the one of communication ports [ID:COM] box is highlighted in sky blue. The device is now connected with the PC and ready to download the binary files in it.



4. Start downloading the binary files into the device by clicking Start button on the screen.

The green colored "PASS!" sign will appear on the upper-left box if the binary files have been successfully downloaded into the device.



- 5. Disconnect the device from the Data cable.
- **6**. Once the device boots up, you can check the version of the binary file or name by pressing the following code in sequence; *#1234#

You can perform Factory data Reset by Settings → General Management → Reset

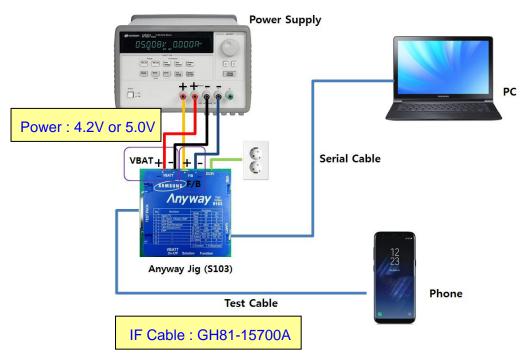
Caution. Never disconnect during the S/W downloading.

6-3. IMEI writing

6-3-1. Preparation

- New IMEI writing Program has been released.
- Supported Model: Models which CAB files are uploaded on HHPsvc INI File category, instead of ini file.
- Refer to below IMEI writing procedure.

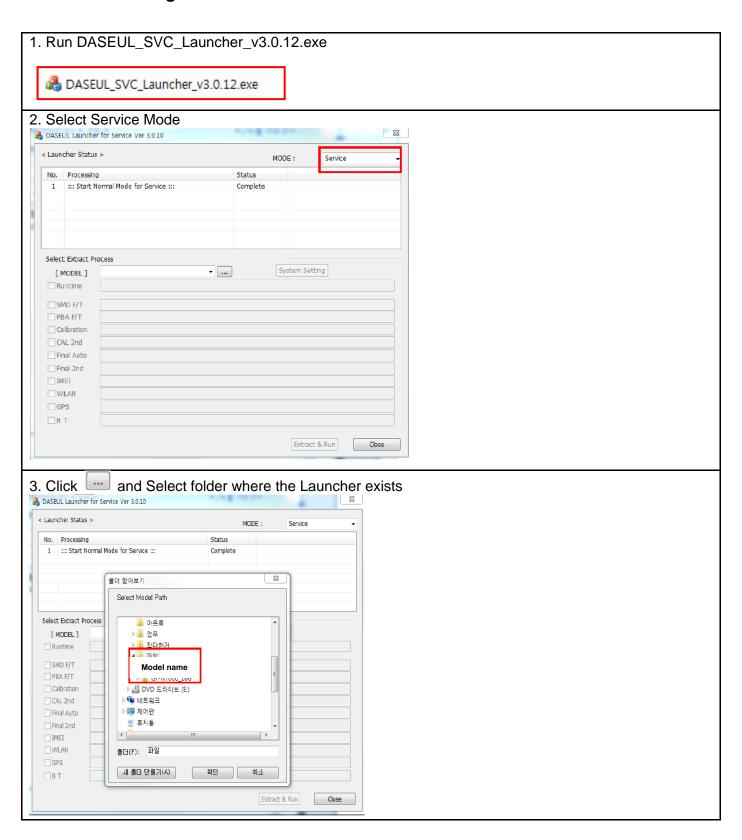
- H/W



- S/W

- 3/ **	
① Library Install	To use Daseul, library files should be installed. Refer to SVC Bulletin "(11-82) Daseul (New IMEI writing Program) Library Install guide_rev1.0"
②Launcher	DASEUL_SVC_Launcher_v3.0.12 or higher -Uploaded on HHPsvc Notice
3 Runtime File	1. DASEUL_IMEI_ALL_Runtime_3.1.281.0_r00405.CAB or higher -Uploaded on HHPsvc Notice 2. Make 'ModelName' folder at the same position with launcher & Runtime file. DASEUL_IMEI_ALL_Runtime_3.1.281.0_r00405.CAB DASEUL_Launcher_v4.0.0.exe SM-G955U_VZW(SIM)_IMEI_Ver_3.1.278.2.CAB
4Model File	Copy Model File under the 'Model Name' folder

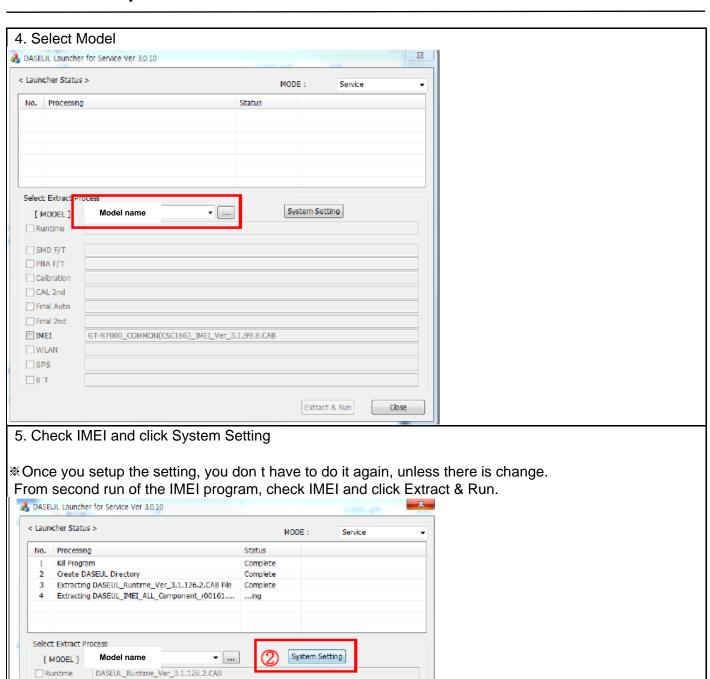
6-3-2. IMEI writing Process



SMD F/T
PBA F/T
Calibration
CAL 2nd

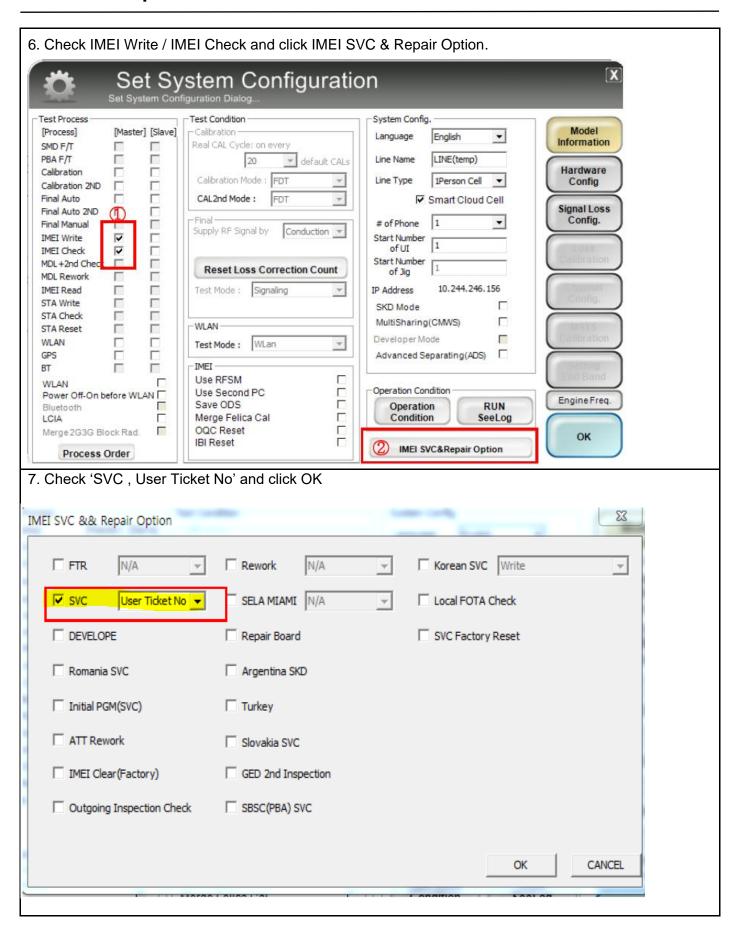
IMEI
WLAN
GPS
B T

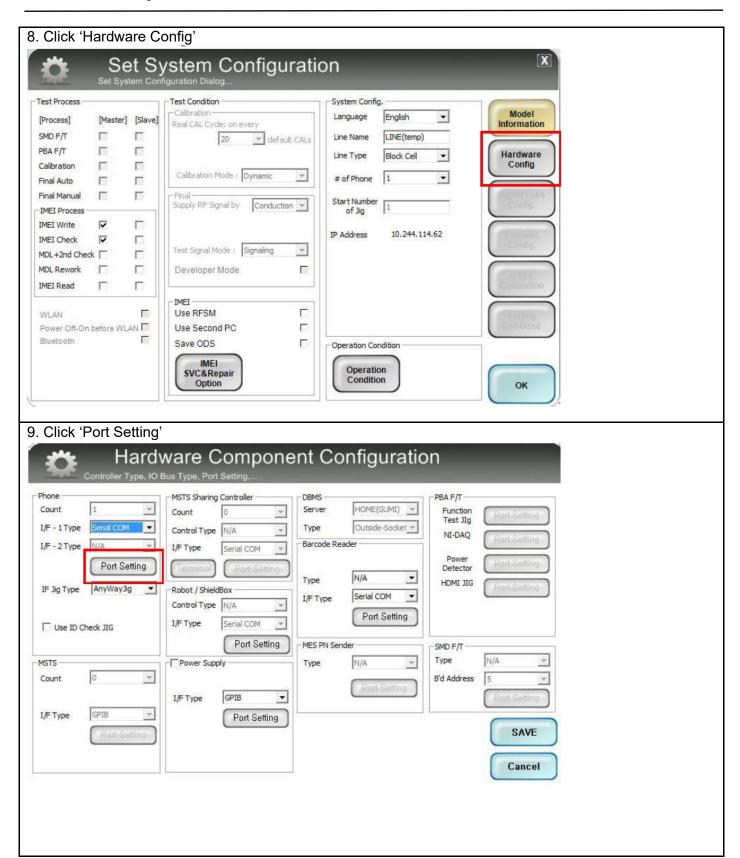
r00161 | GT-N7000_COMMON(CSC16G)_IMEI_Ver_3.1.99.8.CAB

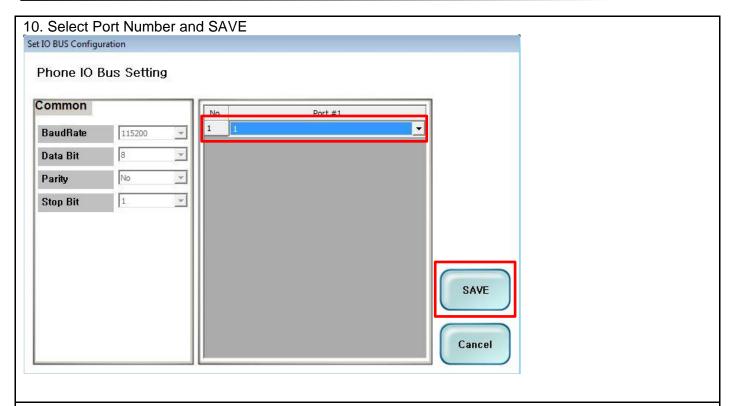


Extract & Run

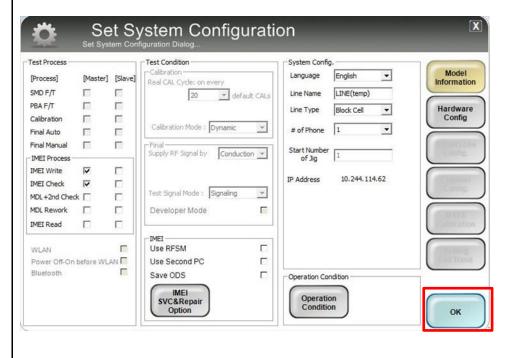
Close

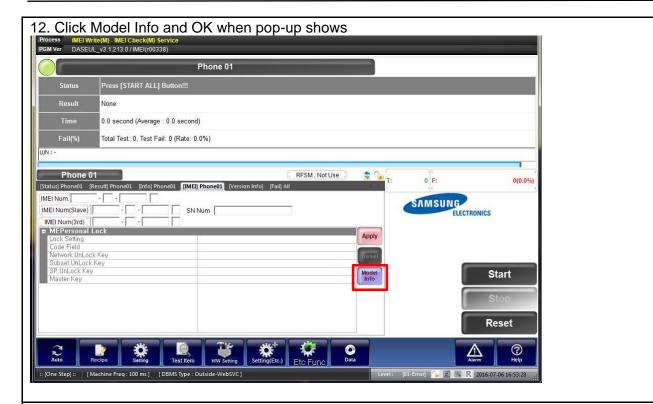






11.Click OK to proceed



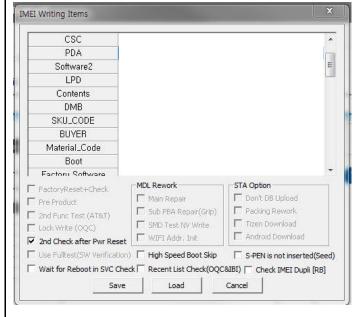


13. Click OK

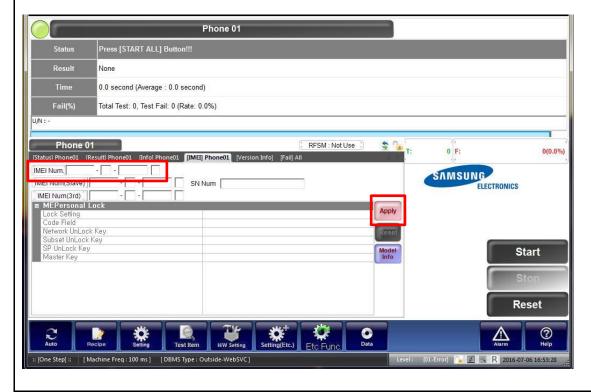


14. Input SKU_CODE and BUYER, then click Save button.

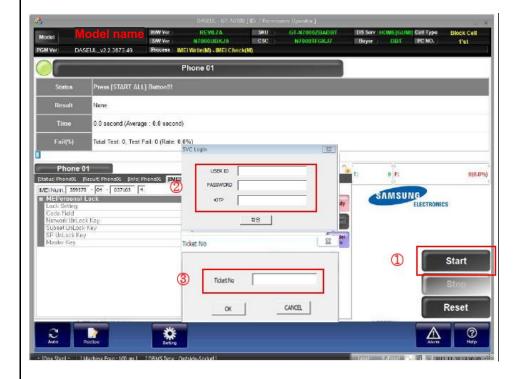
※ Refer to HHPsvc→IMEI Review to check SKU Code and buyer



15. Input IMEI Number and click Apply







X OTP(One time Password): OTP is valid for 6 hours.

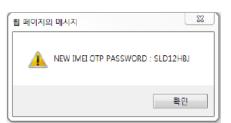
After that, you can get new OTP by click the "Forgotten your IMEI OTP PW or Crete new IMEI OTP PW" button.

HHP svc HOME

DRM Client Download (for NASCA ActiveX / for NASCA 32Bit OS / for NASCA 64Bit OS)

IMEI OTP PASSWORD : Not available

Forgotten your IMEI OTP PW or Create new IMEI OTP PW



- 17. Connect the phone to Anyway JIG
- When you connect the phone, the phone should be turned off.
 After connecting the phone, the phone will be booted automatically.
- 18. IMEI Writing Proceeding



19. IMEI Writing Success



9. Reference Abbreviation

Reference Abbreviation

— AAC: Advanced Audio Coding.— AVC: Advanced Video Coding.

- BER: Bit Error Rate

- BPSK: Binary Phase Shift Keying

- CA: Conditional Access

— CDM : Code Division Multiplexing

- C/I: Carrier to Interference

DMB : Digital Multimedia Broadcasting

EN: European StandardES: Elementary Stream

- ETSI: European Telecommunications Standards Institute

- MPEG: Moving Picture Experts Group

- PN: Pseudo-random Noise

— PS : Pilot Symbol

— QPSK: Quadrature Phase Shift Keying

RS : Reed-SolomonSI : Service Information

- TDM: Time Division Multiplexing

— TS : Transport Stream